Low Voltage Precision Adjustable Shunt Regulator

TLV431, NCV431, SCV431

The TLV431A, B and C series are precision low voltage shunt regulators that are programmable over a wide voltage range of 1.24 V to 16 V. The TLV431A series features a guaranteed reference accuracy of ±1.0% at 25 °C and ±2.0% over the entire industrial temperature range of −40 °C to 85 °C. The TLV431B series features higher reference accuracy of ±0.5% and ±1.0% respectively. For the TLV431C series, the accuracy is even higher. It is ±0.2% and ±1.0% respectively. These devices exhibit a sharp low current turn-on characteristic with a low dynamic impedance of 0.20 Ω over an operating current range of 100 μA to 20 mA. This combination of features makes this series an excellent replacement for zener diodes in numerous applications circuits that require a precise reference voltage. When combined with an optocoupler, the TLV431A/B/C can be used as an error amplifier for controlling the feedback loop in isolated low output voltage (3.0 V to 3.3 V) switching power supplies. These devices are available in economical TO-92-3 and micro size TSOP-5 and SOT-23-3 packages.

Features

- Programmable Output Voltage Range of 1.24 V to 16 V
- Voltage Reference Tolerance ±1.0% for A Series, ±0.5% for B Series and ±0.2% for C Series
- Sharp Low Current Turn-On Characteristic
- Low Dynamic Output Impedance of 0.20 Ω from 100 μA to 20 mA
- Wide Operating Current Range of 50 μA to 20 mA
- Micro Miniature TSOP-5, SOT-23-3 and TO-92-3 Packages
- NCV and SCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free and Halide-Free Devices

Applications

- Low Output Voltage (3.0 V to 3.3 V) Switching Power Supply Error Amplifier
- Adjustable Voltage or Current Linear and Switching Power Supplies
- Voltage Monitoring
- Current Source and Sink Circuits
- Analog and Digital Circuits Requiring Precision References
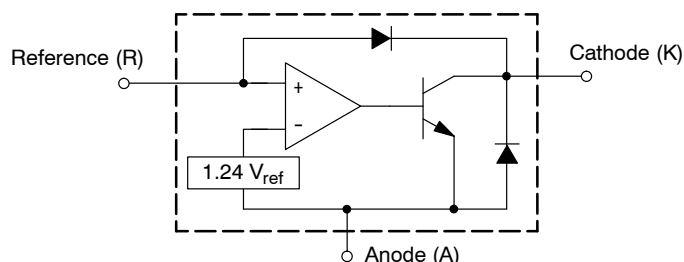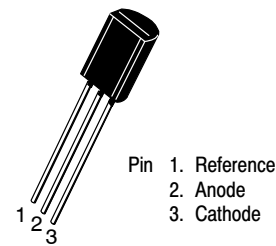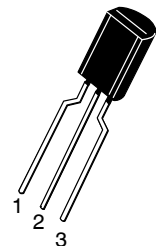- Low Voltage Zener Diode Replacements

Pin 1. Reference
    2. Anode
    3. Cathode

STRAIGHT LEAD BULK PACK

BENT LEAD TAPE & REEL AMMO PACK

TO-92 LP SUFFIX CASE 29-10

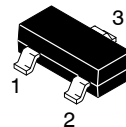**TO-92 LPRA, LPRE, LPRM, LPRP SUFFIX CASE 29-10**
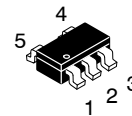
Pin 1. NC
    2. NC
    3. Cathode
    4. Reference
    5. Anode

TSOP-5 SN SUFFIX CASE 483

Pin 1. Reference
    2. Cathode
    3. Anode

SOT-23 SN1 SUFFIX CASE 318
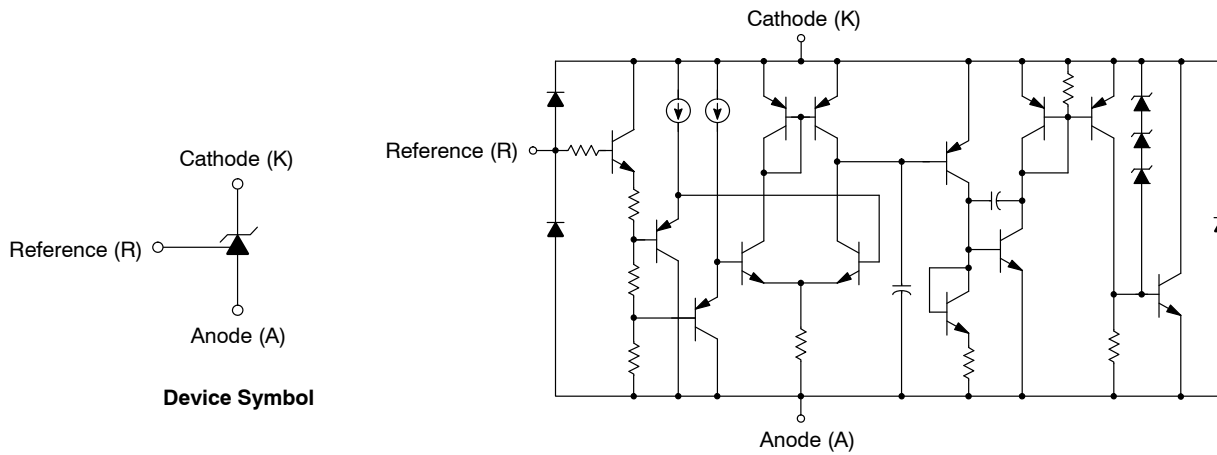
ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 14 of this data sheet.

NOTE: Some of the devices on this data sheet have been **DISCONTINUED**. Please refer to the table on page 14.

DEVICE MARKING INFORMATION AND PIN CONNECTIONS

See general marking information in the device marking section on page 13 of this data sheet.

Figure 1. Representative Block Diagram

TLV431, NCV431, SCV431

Cathode (K)

Reference (R)

Anode (A)

Device Symbol

Cathode (K)

Reference (R)

Anode (A)

The device contains 13 active transistors.

Figure 2. Representative Device Symbol and Schematic Diagram

MAXIMUM RATINGS (Full operating ambient temperature range applies, unless otherwise noted)

Rating	Symbol	Value	Unit
Cathode to Anode Voltage	V_{KA}	18	V
Cathode Current Range, Continuous	I_K	−20 to 25	mA
Reference Input Current Range, Continuous	I_{ref}	− 0.05 to 10	mA
Thermal Characteristics 　LP Suffix Package, TO-92-3 Package 　　Thermal Resistance, Junction-to-Ambient 　　Thermal Resistance, Junction-to-Case 　SN Suffix Package, TSOP-5 Package 　　Thermal Resistance, Junction-to-Ambient 　SN1 Suffix Package, SOT-23-3 Package 　　Thermal Resistance, Junction-to-Ambient	 $R_{\theta JA}$ $R_{\theta JC}$ $R_{\theta JA}$ $R_{\theta JA}$	 178 83 226 491	°C/W
Operating Junction Temperature	T_J	150	°C
Operating Ambient Temperature Range　　　　　　　　TLV431 　　　　　　　　　　　　　　　　　　　　　　NCV431, SCV431	T_A	− 40 to 85 − 40 to 125	°C
Storage Temperature Range	T_{stg}	− 65 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

NOTE:　This device series contains ESD protection and exceeds the following tests:
　　　　Human Body Model 2000 V per JEDEC JESD22-A114F, Machine Model Method 200 V per JEDEC JESD22-A115C,
　　　　Charged Device Method 1000 V per JEDEC JESD22-C101E. This device contains latch-up protection and exceeds ±100 mA per
　　　　JEDEC standard JESD78.

$$P_D = \frac{T_{J(max)} - T_A}{R_{\theta JA}}$$

RECOMMENDED OPERATING CONDITIONS

| Condition	Symbol	Min	Max	Unit
Cathode to Anode Voltage	V_{KA}	V_{ref}	16	V
Cathode Current	I_K	0.1	20	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

ELECTRICAL CHARACTERISTICS $(T_A = 25 \,°C$ unless otherwise noted)

Characteristic	Symbol	TLV431A			TLV431B			Unit
		Min	Typ	Max	Min	Typ	Max	
Reference Voltage (Figure 3) $(V_{KA} = V_{ref}, I_K = 10 \text{ mA}, T_A = 25 \,°C)$ $(T_A = T_{low}$ to T_{high}, Note 1)	V_{ref}	1.228 1.215	1.240 –	1.252 1.265	1.234 1.228	1.240 –	1.246 1.252	V
Reference Input Voltage Deviation Over Temperature (Figure 3) $(V_{KA} = V_{ref}, I_K = 10 \text{ mA}, T_A = T_{low}$ to T_{high}, Notes 1, 2, 3)	ΔV_{ref}	–	7.2	20	–	7.2	20	mV
Ration of Reference Input Voltage Change to Cathode Voltage Change (Figure 4) $(V_{KA} = V_{ref}$ to 16 V, $I_K = 10 \text{ mA})$	$\dfrac{\Delta V_{ref}}{\Delta V_{KA}}$	–	–0.6	–1.5	–	–0.6	–1.5	$\dfrac{mV}{V}$
Reference Terminal Current (Figure 4) $(I_K = 10 \text{ mA}, R1 = 10 \text{ k}\Omega, R2 = \text{open})$	I_{ref}	–	0.15	0.3	–	0.15	0.3	µA
Reference Input Current Deviation Over Temperature (Figure 4) $(I_K = 10 \text{ mA}, R1 = 10 \text{ k}\Omega, R2 = \text{open, Notes 1, 2, 3})$	ΔI_{ref}	–	0.04	0.08	–	0.04	0.08	µA
Minimum Cathode Current for Regulation (Figure 3)	$I_{K(min)}$	–	30	80	–	30	80	µA
Off-State Cathode Current (Figure 5) $(V_{KA} = 6.0 \text{ V}, V_{ref} = 0)$ $(V_{KA} = 16 \text{ V}, V_{ref} = 0)$	$I_{K(off)}$	– –	0.01 0.012	0.04 0.05	– –	0.01 0.012	0.04 0.05	µA
Dynamic Impedance (Figure 3) $(V_{KA} = V_{ref}, I_K = 0.1 \text{ mA to } 20 \text{ mA}, f \leq 1.0 \text{ kHz, Note 4})$	$|Z_{KA}|$	–	0.25	0.4	–	0.25	0.4	Ω

1. Ambient temperature range: $T_{low} = -40 \,°C$, $T_{high} = 85 \,°C$.
2. Guaranteed but not tested.
3. The deviation parameters ΔV_{ref} and ΔI_{ref} are defined as the difference between the maximum value and minimum value obtained over the full operating ambient temperature range that applied.

$\Delta V_{ref} = V_{ref} \text{ Max} - V_{ref} \text{ Min}$

$\Delta T_A = T_2 - T_1$
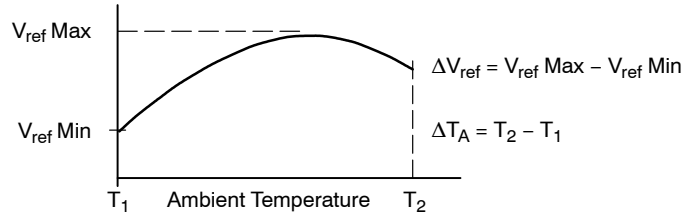
The average temperature coefficient of the reference input voltage, αV_{ref} is defined as:

$$\alpha V_{ref} \left(\frac{\text{ppm}}{°C}\right) = \frac{\left(\dfrac{(\Delta V_{ref})}{V_{ref} \ (T_A = 25°C)} \times 10^6\right)}{\Delta T_A}$$

αV_{ref} can be positive or negative depending on whether V_{ref} Min or V_{ref} Max occurs at the lower ambient temperature, refer to Figure 8.

Example: $\Delta V_{ref} = 7.2 \text{ mV}$ and the slope is positive,

$\quad V_{ref}$ @ 25 °C = 1.241 V

$\quad \Delta T_A = 125 \,°C$

$$\alpha V_{ref} \left(\frac{\text{ppm}}{°C}\right) = \frac{\dfrac{0.0072}{1.241} \times 10^6}{125} = 46 \text{ ppm/°C}$$

4. The dynamic impedance Z_{KA} is defined as:

$$|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_K}$$

When the device is operating with two external resistors, R1 and R2, (refer to Figure 4) the total dynamic impedance of the circuit is given by:

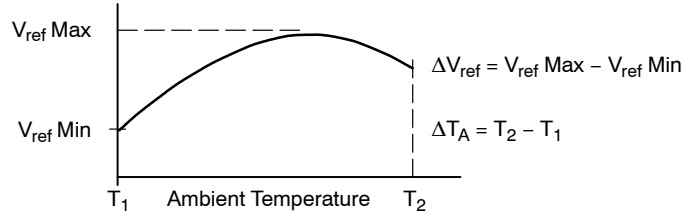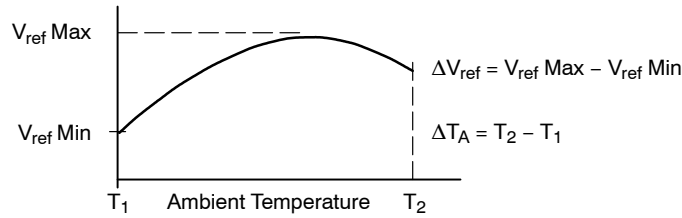$$|Z_{KA}'| = |Z_{KA}| \times \left(1 + \frac{R1}{R2}\right)$$

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted)

Characteristic	Symbol	TLV431C			Unit
		Min	Typ	Max	
Reference Voltage (Figure 3) ($V_{KA} = V_{ref}$, I_K = 10 mA, T_A = 25 °C) ($T_A = T_{low}$ to T_{high}, Note 5)	V_{ref}	1.237 1.228	1.240 –	1.243 1.252	V
Reference Input Voltage Deviation Over Temperature (Figure 3) ($V_{KA} = V_{ref}$, I_K = 10 mA, $T_A = T_{low}$ to T_{high}, Notes 5, 6, 7)	ΔV_{ref}	–	7.2	20	mV
Ration of Reference Input Voltage Change to Cathode Voltage Change (Figure 4) ($V_{KA} = V_{ref}$ to 16 V, I_K = 10 mA)	$\dfrac{\Delta V_{ref}}{\Delta V_{KA}}$	–	−0.6	−1.5	$\dfrac{mV}{V}$
Reference Terminal Current (Figure 4) (I_K = 10 mA, R1 = 10 kΩ, R2 = open)	I_{ref}	–	0.15	0.3	µA
Reference Input Current Deviation Over Temperature (Figure 4) (I_K = 10 mA, R1 = 10 kΩ, R2 = open, Notes 5, 6, 7)	ΔI_{ref}	–	0.04	0.08	µA
Minimum Cathode Current for Regulation (Figure 3)	$I_{K(min)}$	–	30	80	µA
Off-State Cathode Current (Figure 5) (V_{KA} = 6.0 V, V_{ref} = 0) (V_{KA} = 16 V, V_{ref} = 0)	$I_{K(off)}$	– –	0.01 0.012	0.04 0.05	µA
Dynamic Impedance (Figure 3) ($V_{KA} = V_{ref}$, I_K = 0.1 mA to 20 mA, f ≤ 1.0 kHz, Note 8)	$|Z_{KA}|$	–	0.25	0.4	Ω

5. Ambient temperature range: T_{low} = − 40 °C, T_{high} = 85 °C.
6. Guaranteed but not tested.
7. The deviation parameters ΔV_{ref} and ΔI_{ref} are defined as the difference between the maximum value and minimum value obtained over the full operating ambient temperature range that applied.

The average temperature coefficient of the reference input voltage, αV_{ref} is defined as:

$$\alpha V_{ref} \left(\frac{ppm}{°C} \right) = \frac{\left(\dfrac{(\Delta V_{ref})}{V_{ref} \ (T_A = 25°C)} \times 10^6 \right)}{\Delta T_A}$$

αV_{ref} can be positive or negative depending on whether V_{ref} Min or V_{ref} Max occurs at the lower ambient temperature, refer to Figure 8.

Example: ΔV_{ref} = 7.2 mV and the slope is positive,
  V_{ref} @ 25 °C = 1.241 V
  ΔT_A = 125 °C

$$\alpha V_{ref} \left(\frac{ppm}{°C} \right) = \frac{\dfrac{0.0072}{1.241} \times 10^6}{125} = 46 \ ppm/°C$$

8. The dynamic impedance Z_{KA} is defined as:

$$|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_K}$$

When the device is operating with two external resistors, R1 and R2, (refer to Figure 4) the total dynamic impedance of the circuit is given by:

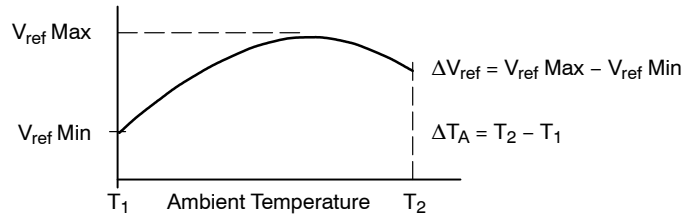$$|Z_{KA}'| = |Z_{KA}| \times \left(1 + \frac{R1}{R2} \right)$$

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted. NCV prefix indicates TSOP package device. SCV prefix indicates SOT-23 package device.)

Characteristic	Symbol	NCV431A, SCV431A			Unit
		Min	Typ	Max	
Reference Voltage (Figure 3) ($V_{KA} = V_{ref}$, I_K = 10 mA, T_A = 25 °C) ($T_A = -40$ °C to 85 °C) ($T_A = -40$ °C to 125 °C)	V_{ref}	1.228 1.215 1.211	1.240 – –	1.252 1.265 1.265	V
Reference Input Voltage Deviation Over Temperature (Figure 3) ($V_{KA} = V_{ref}$, I_K = 10 mA, $T_A = -40$ °C to 85 °C, Notes 9, 10) ($V_{KA} = V_{ref}$, I_K = 10 mA, $T_A = -40$ °C to 125 °C, Notes 9, 10)	ΔV_{ref}	– –	7.2 7.2	20 24	mV
Ration of Reference Input Voltage Change to Cathode Voltage Change (Figure 4) ($V_{KA} = V_{ref}$ to 16 V, I_K = 10 mA)	$\dfrac{\Delta V_{ref}}{\Delta V_{KA}}$	–	–0.6	–1.5	$\dfrac{mV}{V}$
Reference Terminal Current (Figure 4) (I_K = 10 mA, R1 = 10 kΩ, R2 = open)	I_{ref}	–	0.15	0.3	μA
Reference Input Current Deviation Over Temperature (Figure 4) (I_K = 10 mA, R1 = 10 kΩ, R2 = open, $T_A = -40$ °C to 85 °C, Notes 9, 10) (I_K = 10 mA, R1 = 10 kΩ, R2 = open, $T_A = -40$ °C to 125 °C, Notes 9, 10)	ΔI_{ref}	– –	0.04 –	0.08 0.10	μA
Minimum Cathode Current for Regulation (Figure 3)	$I_{K(min)}$	–	30	80	μA
Off-State Cathode Current (Figure 5) (V_{KA} = 6.0 V, V_{ref} = 0) (V_{KA} = 16 V, V_{ref} = 0)	$I_{K(off)}$	– –	0.01 0.012	0.04 0.05	μA
Dynamic Impedance (Figure 3) ($V_{KA} = V_{ref}$, I_K = 0.1 mA to 20 mA, f ≤ 1.0 kHz, Note 11)	$|Z_{KA}|$	–	0.25	0.4	Ω

9. Guaranteed but not tested.
10. The deviation parameters ΔV_{ref} and ΔI_{ref} are defined as the difference between the maximum value and minimum value obtained over the full operating ambient temperature range that applied.

The average temperature coefficient of the reference input voltage, αV_{ref} is defined as:

$$\alpha V_{ref}\left(\frac{ppm}{°C}\right) = \frac{\left(\dfrac{(\Delta V_{ref})}{V_{ref}\ (T_A = 25°C)} \times 10^6\right)}{\Delta T_A}$$

αV_{ref} can be positive or negative depending on whether V_{ref} Min or V_{ref} Max occurs at the lower ambient temperature, refer to Figure 8.

Example: ΔV_{ref} = 7.2 mV and the slope is positive,
$\quad\quad$ V_{ref} @ 25 °C = 1.241 V
$\quad\quad$ ΔT_A = 125 °C

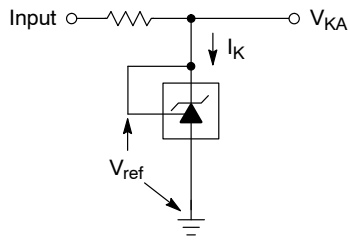$$\alpha V_{ref}\left(\frac{ppm}{°C}\right) = \frac{\dfrac{0.0072}{1.241} \times 10^6}{125} = 46\ ppm/°C$$

11. The dynamic impedance Z_{KA} is defined as:
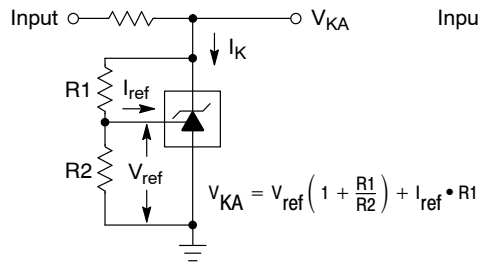
$$|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_K}$$

When the device is operating with two external resistors, R1 and R2, (refer to Figure 4) the total dynamic impedance of the circuit is given by:

$$|Z_{KA}'| = |Z_{KA}| \times \left(1 + \frac{R1}{R2}\right)$$

TLV431, NCV431, SCV431

ELECTRICAL CHARACTERISTICS (T_A = 25 °C unless otherwise noted. NCV prefix indicates TSOP package device. SCV prefix indicates SOT-23 package device.)

Characteristic	Symbol	NCV431B, SCV431B			Unit
		Min	Typ	Max	
Reference Voltage (Figure 3) ($V_{KA} = V_{ref}$, I_K = 10 mA, T_A = 25 °C) ($T_A = -40$ °C to 85 °C) ($T_A = -40$ °C to 125 °C)	V_{ref}	1.234 1.228 1.224	1.240 – –	1.246 1.252 1.252	V
Reference Input Voltage Deviation Over Temperature (Figure 3) ($V_{KA} = V_{ref}$, I_K= 10 mA, $T_A = -40$ °C to 85 °C, Notes 9, 10) ($V_{KA} = V_{ref}$, I_K= 10 mA, $T_A = -40$ °C to 125 °C, Notes 9, 10)	ΔV_{ref}	– –	7.2 7.2	20 24	mV
Ration of Reference Input Voltage Change to Cathode Voltage Change (Figure 4) ($V_{KA} = V_{ref}$ to 16 V, I_K= 10 mA)	$\dfrac{\Delta V_{ref}}{\Delta V_{KA}}$	–	–0.6	–1.5	$\dfrac{mV}{V}$
Reference Terminal Current (Figure 4) (I_K = 10 mA, R1 = 10 kΩ, R2 = open)	I_{ref}	–	0.15	0.3	µA
Reference Input Current Deviation Over Temperature (Figure 4) (I_K = 10 mA, R1 = 10 kΩ, R2 = open, $T_A = -40$ °C to 85 °C, Notes 12, 13) (I_K = 10 mA, R1 = 10 kΩ, R2 = open, $T_A = -40$ °C to 125 °C, Notes 12, 13)	ΔI_{ref}	– –	0.04 –	0.08 0.10	µA
Minimum Cathode Current for Regulation (Figure 3)	$I_{K(min)}$	–	30	80	µA
Off-State Cathode Current (Figure 5) (V_{KA} = 6.0 V, V_{ref} = 0) (V_{KA} = 16 V, V_{ref} = 0)	$I_{K(off)}$	– –	0.01 0.012	0.04 0.05	µA
Dynamic Impedance (Figure 3) ($V_{KA} = V_{ref}$, I_K =0.1 mA to 20 mA, f ≤ 1.0 kHz, Note 14)	$|Z_{KA}|$	–	0.25	0.4	Ω

12. Guaranteed but not tested.
13. The deviation parameters ΔV_{ref} and ΔI_{ref} are defined as the difference between the maximum value and minimum value obtained over the full operating ambient temperature range that applied.

The average temperature coefficient of the reference input voltage, αV_{ref} is defined as:

$$\alpha V_{ref} \left(\frac{ppm}{°C} \right) = \frac{\left(\dfrac{(\Delta V_{ref})}{V_{ref}\ (T_A = 25°C)} \times 10^6 \right)}{\Delta T_A}$$

αV_{ref} can be positive or negative depending on whether V_{ref} Min or V_{ref} Max occurs at the lower ambient temperature, refer to Figure 8.

Example: ΔV_{ref} = 7.2 mV and the slope is positive,
   V_{ref} @ 25 °C = 1.241 V
   ΔT_A = 125 °C

$$\alpha V_{ref} \left(\frac{ppm}{°C} \right) = \frac{\dfrac{0.0072}{1.241} \times 10^6}{125} = 46\ ppm/°C$$

14. The dynamic impedance Z_{KA} is defined as:

$$|Z_{KA}| = \frac{\Delta V_{KA}}{\Delta I_K}$$

When the device is operating with two external resistors, R1 and R2, (refer to Figure 4) the total dynamic impedance of the circuit is given by:

$$|Z_{KA}'| = |Z_{KA}| \times \left(1 + \frac{R1}{R2} \right)$$

Figure 3. Test Circuit for $V_{KA} = V_{ref}$

Figure 4. Test Circuit for $V_{KA} > V_{ref}$

$$V_{KA} = V_{ref}\left(1 + \frac{R1}{R2}\right) + I_{ref} \cdot R1$$
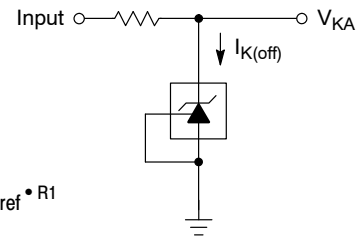
Figure 5. Test Circuit for $I_{K(off)}$
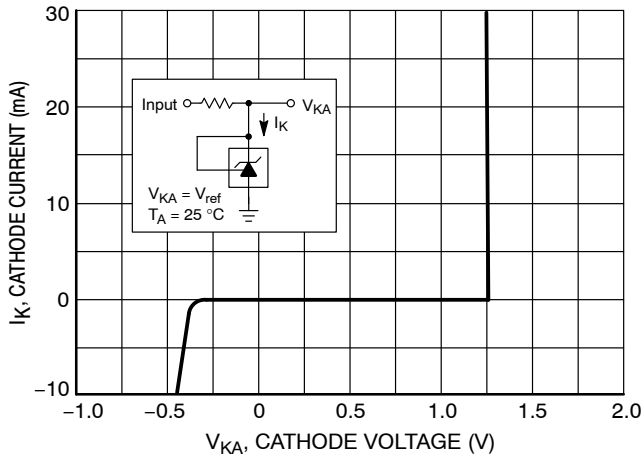
Figure 6. Cathode Current vs. Cathode Voltage
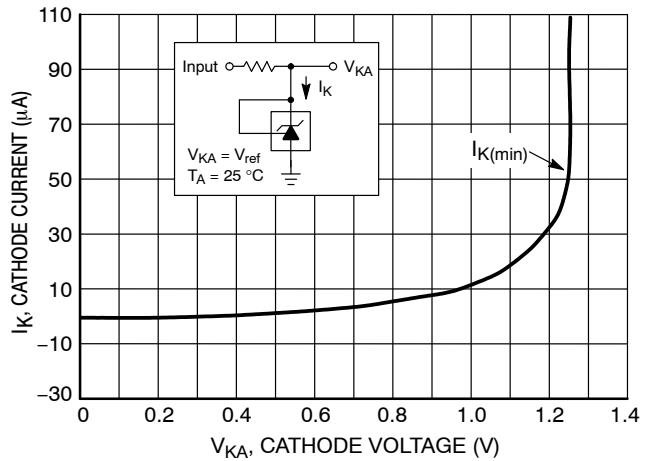
Figure 7. Cathode Current vs. Cathode Voltage
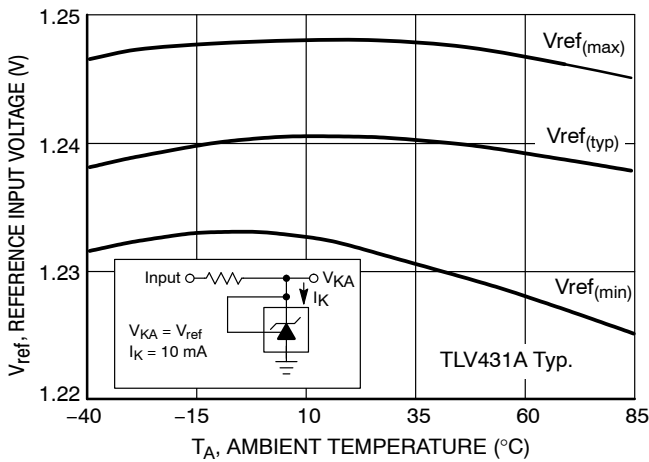
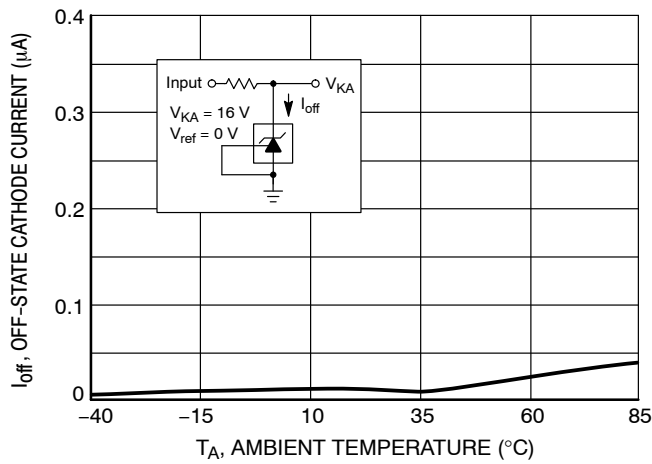**Figure 8. Reference Input Voltage versus Ambient Temperature**
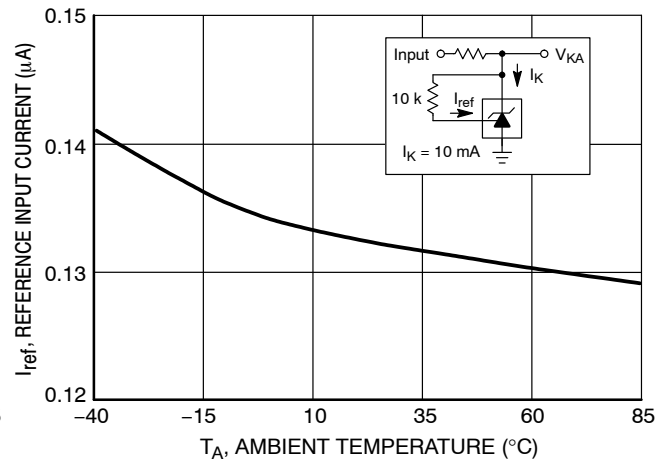
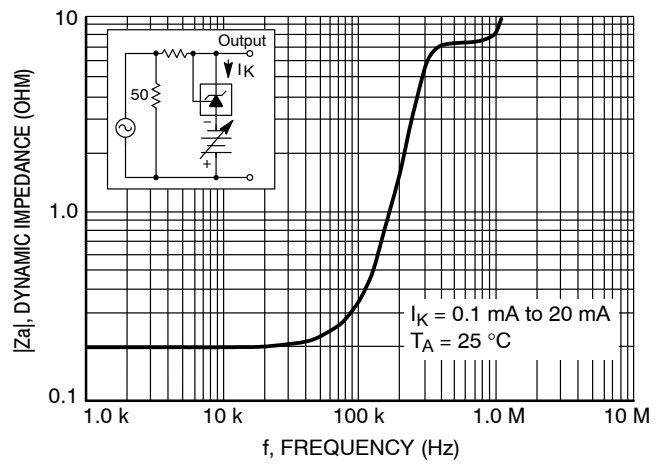**Figure 9. Reference Input Current versus Ambient Temperature**
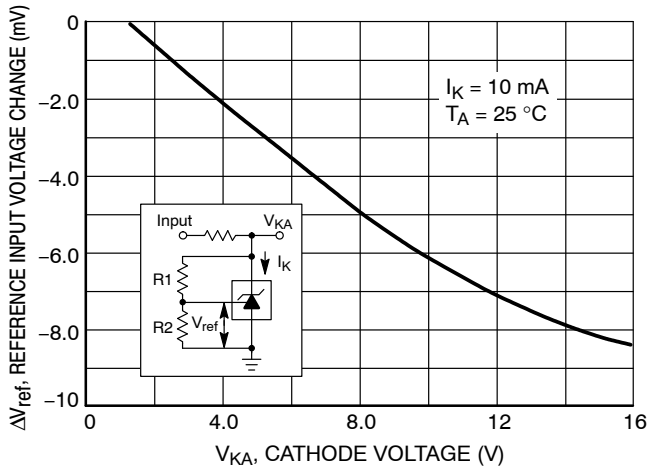
Figure 10. Reference Input Voltage Change
versus Cathode Voltage
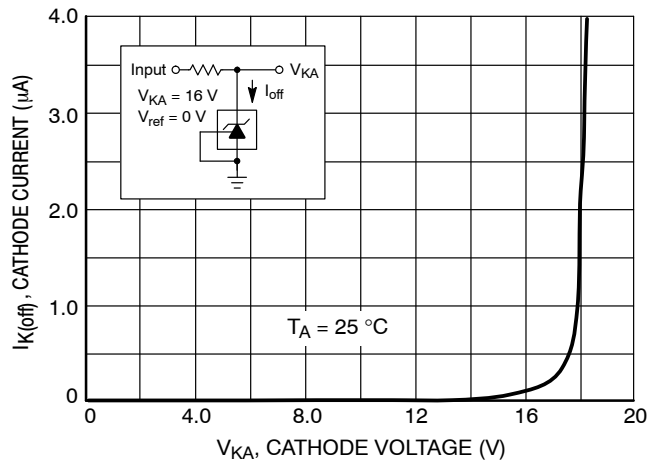
Figure 11. Off-State Cathode Current
versus Cathode Voltage

Figure 12. Off-State Cathode Current versus
Ambient Temperature

Figure 13. Dynamic Impedance versus
Frequency
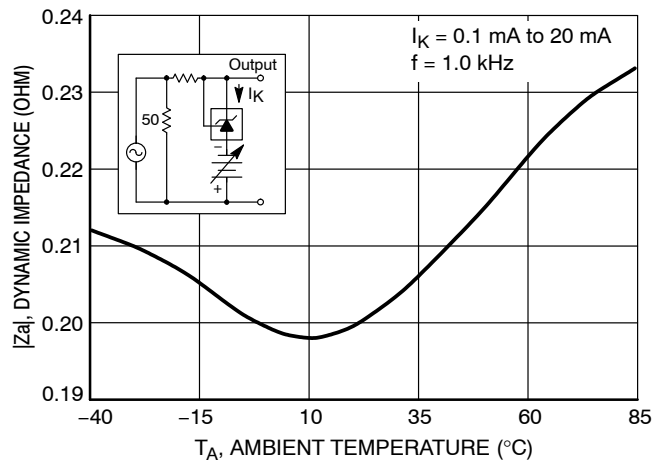
Figure 14. Dynamic Impedance versus
Ambient Temperature
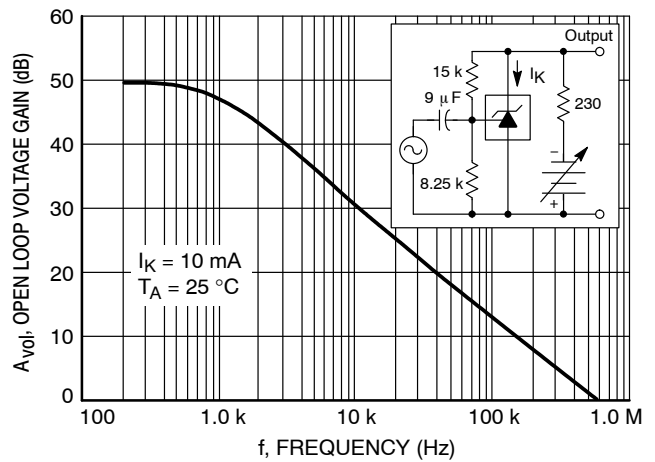
Figure 15. Open-Loop Voltage Gain
versus Frequency
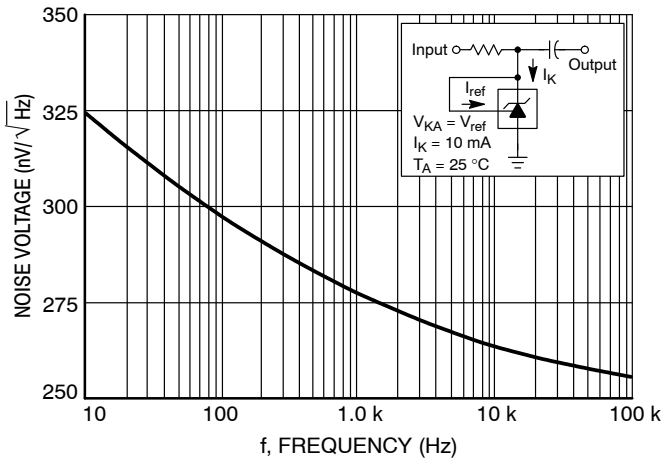
Figure 16. Spectral Noise Density
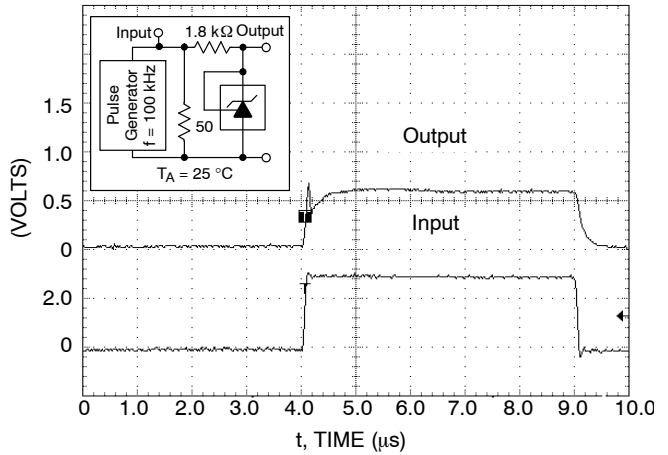
Figure 17. Pulse Response
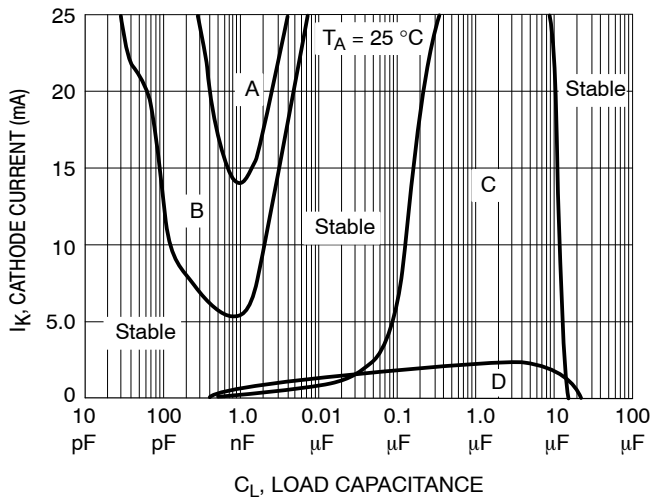
Figure 18. Stability Boundary Conditions
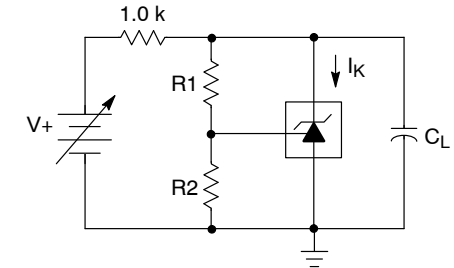
Unstable Regions	V_{KA} (V)	R1 (kΩ)	R2 (kΩ)
A, C	V_{ref}	0	∞
B, D	5.0	30.4	10

Figure 19. Test Circuit for Figure 18

STABILITY

Figures 18 and 19 show the stability boundaries and circuit configurations for the worst case conditions with the load capacitance mounted as close as possible to the device. The required load capacitance for stable operation can vary depending on the operating temperature and capacitor equivalent series resistance (ESR). Ceramic or tantalum surface mount capacitors are recommended for both temperature and ESR. The application circuit stability should be verified over the anticipated operating current and temperature ranges.

TYPICAL APPLICATIONS

$$V_{out} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$
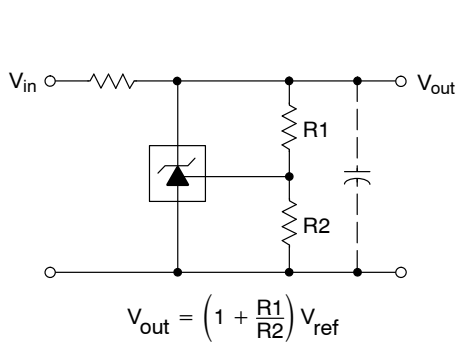
Figure 20. Shunt Regulator

$$V_{out} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$
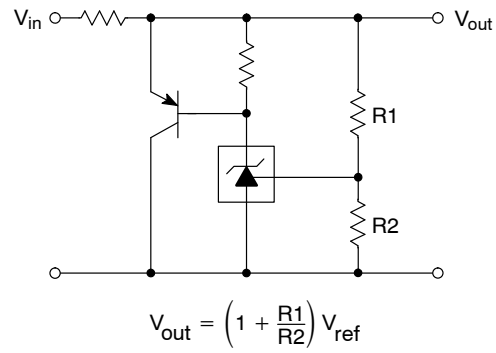
Figure 21. High Current Shunt Regulator

$$V_{out} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$

$$V_{out(min)} = V_{ref} + 5.0\ V$$
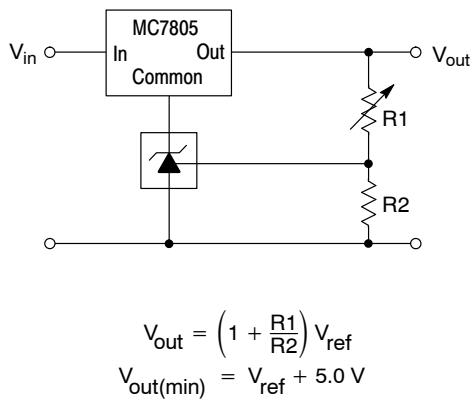
Figure 22. Output Control for a Three Terminal Fixed Regulator

$$V_{out} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$

$$V_{in(min)} = V_{out} + V_{be}$$

$$V_{out(min)} = V_{ref}$$
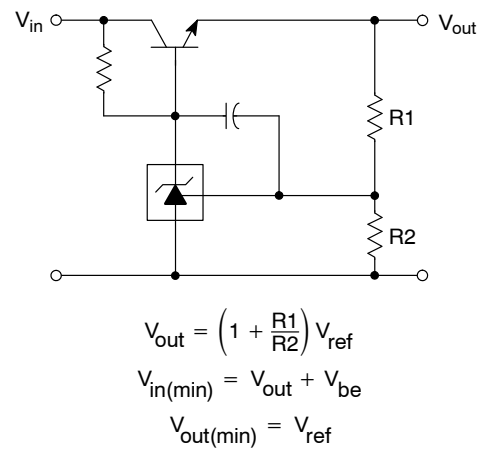
Figure 23. Series Pass Regulator

$$I_{out} = \frac{V_{ref}}{R_{CL}}$$
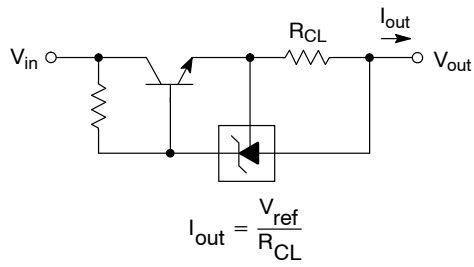
Figure 24. Constant Current Source

$$I_{sink} = \frac{V_{ref}}{R_S}$$
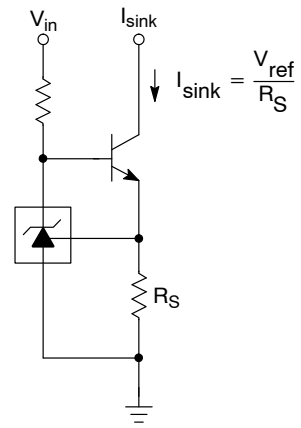
Figure 25. Constant Current Sink

$$V_{out(trip)} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$
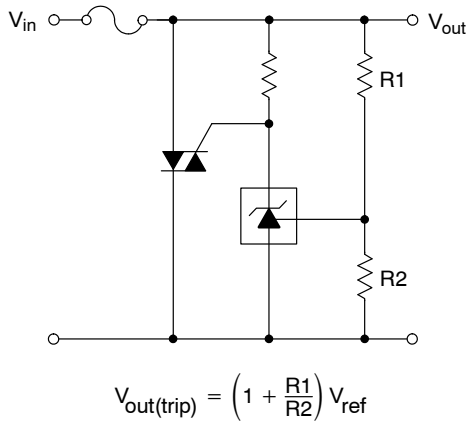
Figure 26. TRIAC Crowbar

$$V_{out(trip)} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$
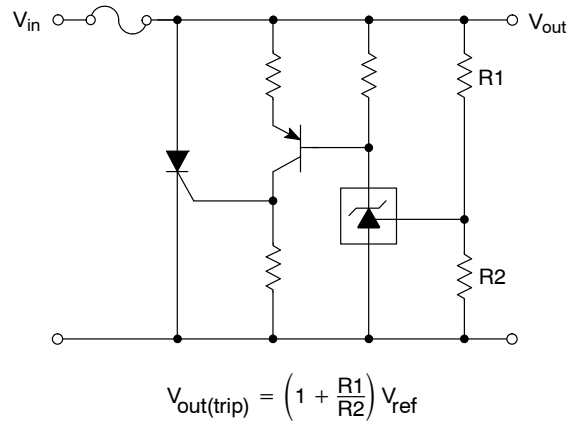
Figure 27. SCR Crowbar
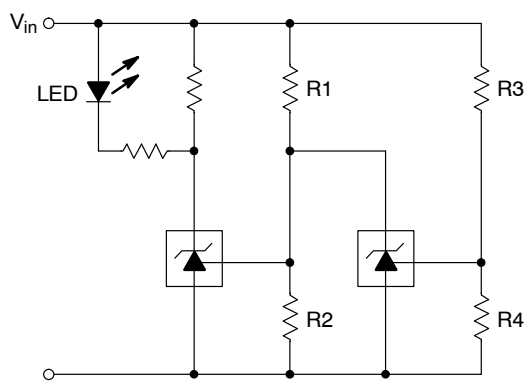
L.E.D. indicator is 'ON' when V_{in} is between the upper and lower limits,

$$\text{Lower limit} = \left(1 + \frac{R1}{R2}\right) V_{ref}$$

$$\text{Upper limit} = \left(1 + \frac{R3}{R4}\right) V_{ref}$$

Figure 28. Voltage Monitor

$$R_x = V_{out} \bullet \frac{\Omega}{V} \text{ Range}$$
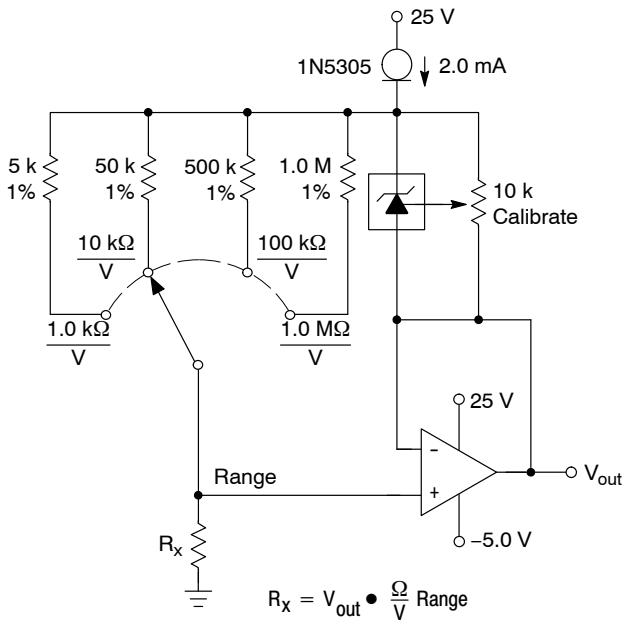
Figure 29. Linear Ohmmeter
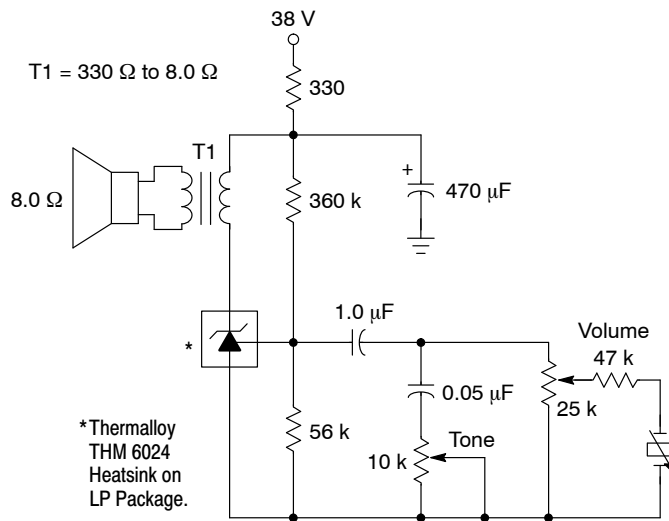
Figure 30. Simple 400 mW Phono Amplifier

TLV431, NCV431, SCV431
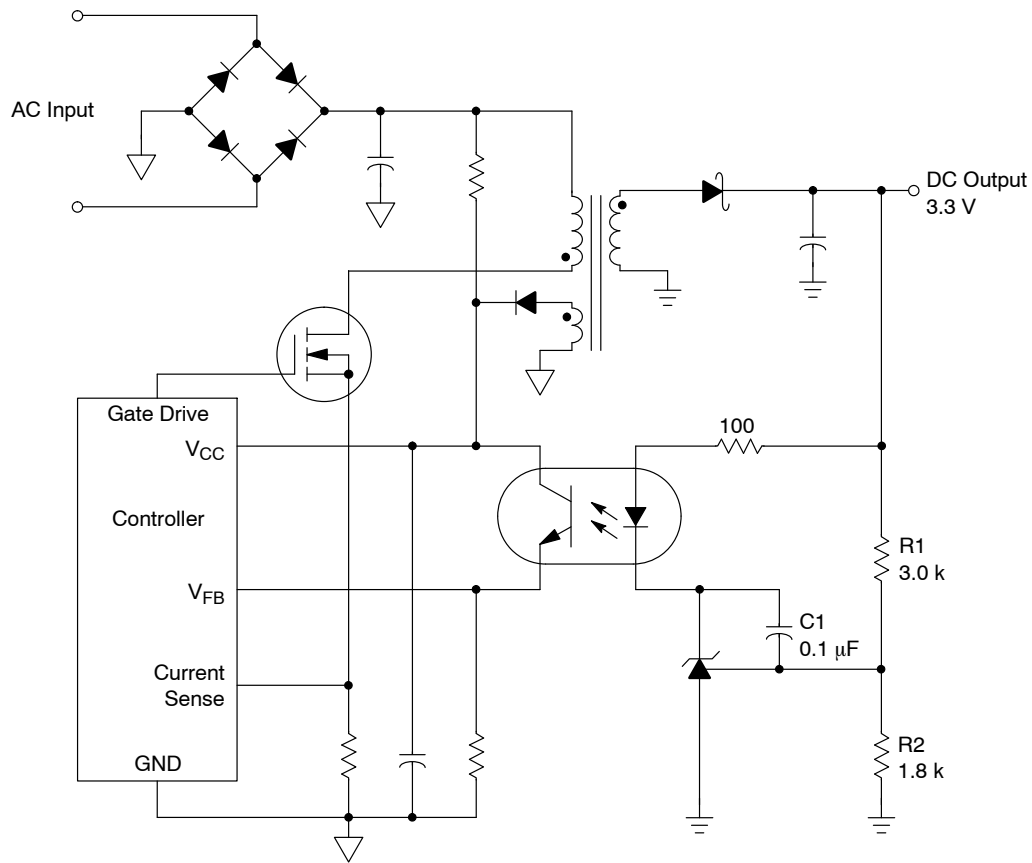
Figure 31. Isolated Output Line Powered Switching Power Supply

The above circuit shows the TLV431A/B/C as a compensated amplifier controlling the feedback loop of an isolated output line powered switching regulator. The output voltage is programmed to 3.3 V by the resistors values selected for R1 and R2. The minimum output voltage that can be programmed with this circuit is 2.64 V, and is limited by the sum of the reference voltage (1.24 V) and the forward drop of the optocoupler light emitting diode (1.4 V). Capacitor C1 provides loop compensation.

PIN CONNECTIONS AND DEVICE MARKING

TO−92
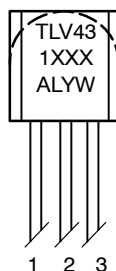
1. Reference
2. Anode
3. Cathode

TSOP−5

NC 1 • 5 Anode
NC 2 4 Reference
Cathode 3 4 Reference
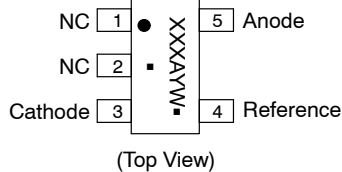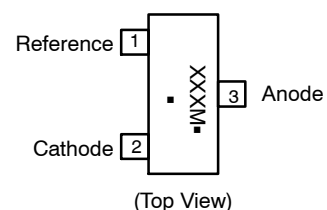
(Top View)

XXX	= Specific Device Code
A	= Assembly Location
Y	= Year
L	= Wafer Lot
W	= Work Week
▪	= Pb-Free Package

(Note: Microdot may be in either location)

SOT−23−3

Reference 1
Cathode 2 3 Anode

(Top View)

XXX	= Specific Device Code
M	= Date Code
▪	= Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Device Code	Package	Shipping†
TLV431ALPRAG	ALP	TO-92-3 (Pb-Free)	2000 / Tape & Reel
TLV431ASNT1G	RAA	TSOP-5 (Pb-Free, Halide-Free)	3000 / Tape & Reel
TLV431ASN1T1G	RAF	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel
TLV431BSNT1G	RAH	TSOP-5 (Pb-Free, Halide-Free)	3000 / Tape & Reel
TLV431BSN1T1G	RAG	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel
TLV431CSN1T1G	AAN	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel
SCV431ASN1T1G*	RAE	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel
SCV431BSN1T1G*	RAC	SOT-23-3 (Pb-Free, Halide-Free)	3000 / Tape & Reel
NCV431ASNT1G*	ACH	TSOP-5 (Pb-Free, Halide-Free)	3000 / Tape & Reel
NCV431BSNT1G*	AD6	TSOP-5 (Pb-Free, Halide-Free)	3000 / Tape & Reel

DISCONTINUED (Note 15)

Device	Device Code	Package	Shipping†
TLV431ALPG	ALP	TO-92-3 (Pb-Free)	6000 / Box
TLV431ALPREG	ALP	TO-92-3 (Pb-Free)	2000 / Tape & Reel
TLV431ALPRMG	ALP	TO-92-3 (Pb-Free)	2000 / Ammo Pack
TLV431ALPRPG	ALP	TO-92-3 (Pb-Free)	2000 / Ammo Pack
TLV431BLPG	BLP	TO-92-3 (Pb-Free)	6000 / Box
TLV431BLPRAG	BLP	TO-92-3 (Pb-Free)	2000 / Tape & Reel
TLV431BLPREG	BLP	TO-92-3 (Pb-Free)	2000 / Tape & Reel
TLV431BLPRMG	BLP	TO-92-3 (Pb-Free)	2000 / Ammo Pack
TLV431BLPRPG	BLP	TO-92-3 (Pb-Free)	2000 / Ammo Pack

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*SCV, NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

15. **DISCONTINUED:** These devices are not recommended for new design. Please contact your **onsemi** representative for information. The most current information on these devices may be available on www.onsemi.com.

REVISION HISTORY

Revision	Description of Changes	Date
28	• Rebranded the Data Sheet to **onsemi** format. • TLV431ALPG, TLV431ALPREG, TLV431ALPRMG, TLV431ALPRPG, TLV431BLPG, TLV431BLPRAG, TLV431BLPREG, TLV431BLPRMG, TLV431BLPRPG OPNs Marked as Discontinued.	6/5/2025
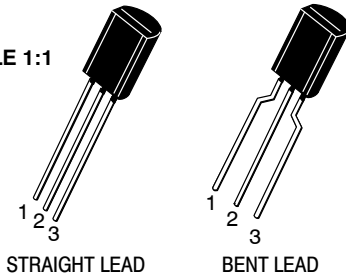
TO−92 (TO−226) 1 WATT
CASE 29−10
ISSUE D

DATE 05 MAR 2021

SCALE 1:1

1 2 3
STRAIGHT LEAD

1 2 3
BENT LEAD

STRAIGHT LEAD

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
4. DIMENSION b AND b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION b2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

END VIEW

TOP VIEW

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	3.75	3.90	4.05
A1	1.28	1.43	1.58
b	0.38	0.465	0.55
b2	0.62	0.70	0.78
c	0.35	0.40	0.45
D	7.85	8.00	8.15
E	4.75	4.90	5.05
E2	3.90	---	---
e	1.27 BSC		
L	13.80	14.00	14.20

⊕ 0.20 Ⓜ B A

3X b

STYLES AND MARKING ON PAGE 3

DOCUMENT NUMBER:	98AON52857E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO−92 (TO−226) 1 WATT		PAGE 1 OF 3

FORMED LEAD

END VIEW

TOP VIEW

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
2. CONTROLLING DIMENSION: MILLIMETERS
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR GATE PROTRUSIONS.
4. DIMENSION b AND b2 DOES NOT INCLUDE DAMBAR PROTRUSION. LEAD WIDTH INCLUDING PROTRUSION SHALL NOT EXCEED 0.20. DIMENSION b2 LOCATED ABOVE THE DAMBAR PORTION OF MIDDLE LEAD.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	3.75	3.90	4.05
A1	1.28	1.43	1.58
b	0.38	0.465	0.55
b2	0.62	0.70	0.78
c	0.35	0.40	0.45
D	7.85	8.00	8.15
E	4.75	4.90	5.05
E2	3.90	---	---
e	2.50 BSC		
L	13.80	14.00	14.20
L2	13.20	13.60	14.00
L3	3.00 REF		

STYLES AND MARKING ON PAGE 3

DOCUMENT NUMBER:	98AON52857E	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO−92 (TO−226) 1 WATT		PAGE 2 OF 3

STYLE 1:
PIN 1. EMITTER
    2. BASE
    3. COLLECTOR

STYLE 2:
PIN 1. BASE
    2. EMITTER
    3. COLLECTOR

STYLE 3:
PIN 1. ANODE
    2. ANODE
    3. CATHODE

STYLE 4:
PIN 1. CATHODE
    2. CATHODE
    3. ANODE

STYLE 5:
PIN 1. DRAIN
    2. SOURCE
    3. GATE

STYLE 6:
PIN 1. GATE
    2. SOURCE & SUBSTRATE
    3. DRAIN

STYLE 7:
PIN 1. SOURCE
    2. DRAIN
    3. GATE

STYLE 8:
PIN 1. DRAIN
    2. GATE
    3. SOURCE & SUBSTRATE

STYLE 9:
PIN 1. BASE 1
    2. EMITTER
    3. BASE 2

STYLE 10:
PIN 1. CATHODE
    2. GATE
    3. ANODE

STYLE 11:
PIN 1. ANODE
    2. CATHODE & ANODE
    3. CATHODE

STYLE 12:
PIN 1. MAIN TERMINAL 1
    2. GATE
    3. MAIN TERMINAL 2

STYLE 13:
PIN 1. ANODE 1
    2. GATE
    3. CATHODE 2

STYLE 14:
PIN 1. EMITTER
    2. COLLECTOR
    3. BASE

STYLE 15:
PIN 1. ANODE 1
    2. CATHODE
    3. ANODE 2

STYLE 16:
PIN 1. ANODE
    2. GATE
    3. CATHODE

STYLE 17:
PIN 1. COLLECTOR
    2. BASE
    3. EMITTER

STYLE 18:
PIN 1. ANODE
    2. CATHODE
    3. NOT CONNECTED

STYLE 19:
PIN 1. GATE
    2. ANODE
    3. CATHODE

STYLE 20:
PIN 1. NOT CONNECTED
    2. CATHODE
    3. ANODE

STYLE 21:
PIN 1. COLLECTOR
    2. EMITTER
    3. BASE

STYLE 22:
PIN 1. SOURCE
    2. GATE
    3. DRAIN

STYLE 23:
PIN 1. GATE
    2. SOURCE
    3. DRAIN

STYLE 24:
PIN 1. EMITTER
    2. COLLECTOR/ANODE
    3. CATHODE

STYLE 25:
PIN 1. MT 1
    2. GATE
    3. MT 2

STYLE 26:
PIN 1. V_{CC}
    2. GROUND 2
    3. OUTPUT

STYLE 27:
PIN 1. MT
    2. SUBSTRATE
    3. MT

STYLE 28:
PIN 1. CATHODE
    2. ANODE
    3. GATE

STYLE 29:
PIN 1. NOT CONNECTED
    2. ANODE
    3. CATHODE

STYLE 30:
PIN 1. DRAIN
    2. GATE
    3. SOURCE

STYLE 31:
PIN 1. GATE
    2. DRAIN
    3. SOURCE

STYLE 32:
PIN 1. BASE
    2. COLLECTOR
    3. EMITTER

STYLE 33:
PIN 1. RETURN
    2. INPUT
    3. OUTPUT

STYLE 34:
PIN 1. INPUT
    2. GROUND
    3. LOGIC

STYLE 35:
PIN 1. GATE
    2. COLLECTOR
    3. EMITTER

**GENERIC
MARKING DIAGRAM***

```
XXXXX
XXXXX
ALYW■
    ■
```
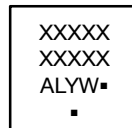
XXXX = Specific Device Code
A   = Assembly Location
L   = Wafer Lot
Y   = Year
W   = Work Week
■   = Pb–Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to
device data sheet for actual part marking.
Pb–Free indicator, "G" or microdot "■", may
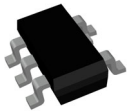or may not be present. Some products may
not follow the Generic Marking.

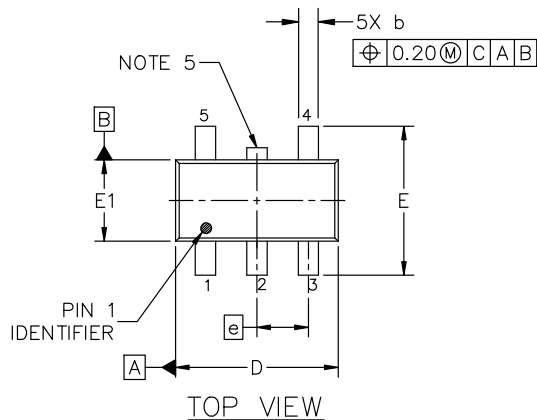**SOT−23 (TO−236) 2.90x1.30x1.00 1.90P**
CASE 318
ISSUE AU

DATE 14 AUG 2024

SCALE 4:1

TOP VIEW

SIDE VIEW

END VIEW

DETAIL "A"
Scale 3:1

SEATING PLANE

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.89	1.00	1.11
A1	0.01	0.06	0.10
b	0.37	0.44	0.50
c	0.08	0.14	0.20
D	2.80	2.90	3.04
E	1.20	1.30	1.40
e	1.78	1.90	2.04
L	0.30	0.43	0.55
L1	0.35	0.54	0.69
H_E	2.10	2.40	2.64
T	0°	− − −	10°

NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSIONS: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

GENERIC MARKING DIAGRAM*

XXXM▪

1
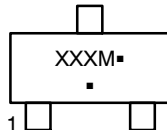
XXX = Specific Device Code
M = Date Code
▪ = Pb−Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED
MOUNTING FOOTPRINT

2.90

3X 0.95

3X 0.56

0.95

PITCH
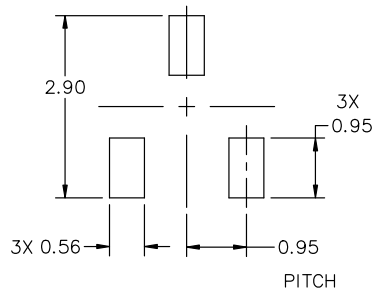
* For additional information on our Pb−Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

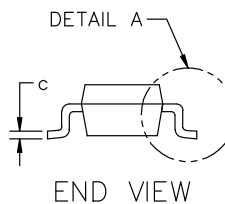| DOCUMENT NUMBER:	98ASB42226B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT−23 (TO−236) 2.90x1.30x1.00 1.90P		PAGE 1 OF 2

SOT−23 (TO−236) 2.90x1.30x1.00 1.90P
CASE 318
ISSUE AU

DATE 14 AUG 2024

STYLE 1 THRU 5:
CANCELLED

STYLE 6:
PIN 1. BASE
2. EMITTER
3. COLLECTOR

STYLE 7:
PIN 1. EMITTER
2. BASE
3. COLLECTOR

STYLE 8:
PIN 1. ANODE
2. NO CONNECTION
3. CATHODE

STYLE 9:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 10:
PIN 1. DRAIN
2. SOURCE
3. GATE

STYLE 11:
PIN 1. ANODE
2. CATHODE
3. CATHODE−ANODE

STYLE 12:
PIN 1. CATHODE
2. CATHODE
3. ANODE

STYLE 13:
PIN 1. SOURCE
2. DRAIN
3. GATE

STYLE 14:
PIN 1. CATHODE
2. GATE
3. ANODE

STYLE 15:
PIN 1. GATE
2. CATHODE
3. ANODE

STYLE 16:
PIN 1. ANODE
2. CATHODE
3. CATHODE

STYLE 17:
PIN 1. NO CONNECTION
2. ANODE
3. CATHODE

STYLE 18:
PIN 1. NO CONNECTION
2. CATHODE
3. ANODE

STYLE 19:
PIN 1. CATHODE
2. ANODE
3. CATHODE−ANODE

STYLE 20:
PIN 1. CATHODE
2. ANODE
3. GATE

STYLE 21:
PIN 1. GATE
2. SOURCE
3. DRAIN

STYLE 22:
PIN 1. RETURN
2. OUTPUT
3. INPUT

STYLE 23:
PIN 1. ANODE
2. ANODE
3. CATHODE

STYLE 24:
PIN 1. GATE
2. DRAIN
3. SOURCE

STYLE 25:
PIN 1. ANODE
2. CATHODE
3. GATE

STYLE 26:
PIN 1. CATHODE
2. ANODE
3. NO CONNECTION

STYLE 27:
PIN 1. CATHODE
2. CATHODE
3. CATHODE

STYLE 28:
PIN 1. ANODE
2. ANODE
3. ANODE

DOCUMENT NUMBER:	98ASB42226B	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT−23 (TO−236) 2.90x1.30x1.00 1.90P		PAGE 2 OF 2

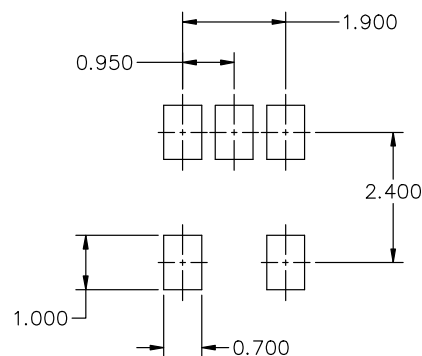**TSOP−5 3.00x1.50x0.95, 0.95P**
CASE 483
ISSUE P

DATE 01 APR 2024
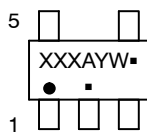
NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5−2018.
2. ALL DIMENSION ARE IN MILLIMETERS (ANGLES IN DEGREES).
3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
4. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS OF GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSION D.
5. OPTIONAL CONSTRUCTION: AN ADDITIONAL TRIMMED LEAD IS ALLOWED IN THIS LOCATION. TRIMMED LEAD NOT TO EXTEND MORE THAN 0.2 FROM BODY.

5X b
⊕ 0.20 Ⓜ C A B

NOTE 5

TOP VIEW

SIDE VIEW

DETAIL A

END VIEW

0.250 GAUGE PLANE

DETAIL "A"
SCALE 2:1

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	0.900	1.000	1.100
A1	0.010	0.055	0.100
A2	0.950 REF.		
b	0.250	0.375	0.500
c	0.100	0.180	0.260
D	2.850	3.000	3.150
E	2.500	2.750	3.000
E1	1.350	1.500	1.650
e	0.950 BSC		
L	0.200	0.400	0.600
θ	0°	5°	10°

GENERIC MARKING DIAGRAM*

Analog

XXXAYW■

Discrete/Logic

XXX M■

XXX = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
■ = Pb−Free Package

XXX = Specific Device Code
M = Date Code
■ = Pb−Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED MOUNTING FOOTPRINT*

1.900
0.950
2.400
1.000
0.700

* FOR ADDITIONAL INFORMATION ON OUR Pb−FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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DESCRIPTION:	TSOP−5 3.00x1.50x0.95, 0.95P		PAGE 1 OF 1

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